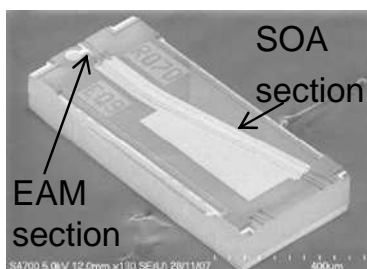


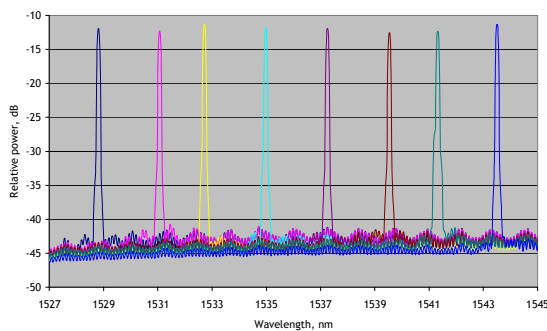
one facet. This is achieved in a structure featuring curved waveguides, mode expansion and ultra-low antireflection coatings. At high manufacturing volumes the RSOA chip is expected to be a little more expensive than a Fabry-Perot laser, probably comparable to a DFB laser, but not as expensive as a tuneable laser. For 10Gbit/s data rates a better solution is use an integrated SOA-REAM for the reflective ONU transmitter. This provides the amplification advantage of the SOA but with the modulation speed of the EAM. An integrated SOA-REAM has been developed on 6th Framework project PIEMAN and has proved capable of long reach transmission over 80km at 10Gbit/s².

Fig. 2: Integrated SOA/REAM Chip for reflective ONU



The alternative to the reflective architecture is to use tuneable lasers within the ONU. A tuneable laser designed at CIP for long reach DWDM access has been recently been demonstrated on the PIEMAN test-bed at the UCC Tyndall Centre³. An objective of the laser design was to eliminate the need for either internal wavelength lockers or network centric wavelength stabilisation. Ideally the laser wavelength needs only to be set once when the ONU is first brought into service. To achieve this high level of inherent stability a hybrid integrated laser design has been developed featuring an athermal tuning filter set by a micro-motor of a type produced for consumer applications. A side mode suppression ratio of better than 30dB is achieved over the required tuning range, as shown in Fig 3.

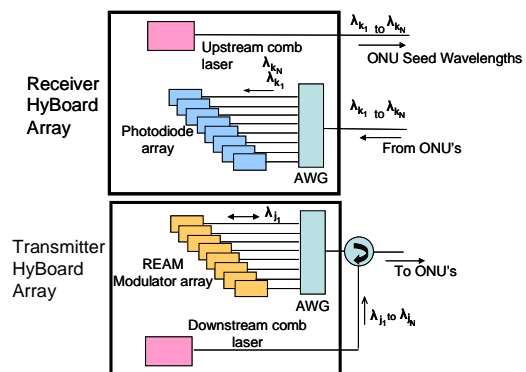
Fig. 3: Tuning spectrum of hybrid integrated ONU laser



Within the OLT of a WDM-PON there is also a need to reduce optical component costs. At the OLT photonic integration offers a great opportunity not only to reduce cost and size but also eliminate the fibre

spaghetti of a discrete component solution. Hybrid integration has particular attractions because it provides the best economics for combining passive elements, such as AWG's and active devices, including lasers, modulators and amplifiers. A critical feature of the hybrid integration approach is the ability to self align the InP based active devices and the silica on silicon passive components⁴. This requires the use of mode expansion on the active elements along with various lithographically defined alignment features on the silicon motherboard and sub-mounts. With this approach fully automated "pick and place" assembly is a long term possibility to reduce costs. A prototype 32 wavelength DWDM laser source using hybrid integration has recently been demonstrated in a WDM-PON⁵. Fig 4 shows how both the footprint and number of fibre connections within the equipment of a reflective WDM-PON OLT could be further reduced using photonic integration.

Fig. 4: Possible Hybrid Integrated Modules for WDM OLT



Discussion and Conclusion

DWDM technologies will be required in future optical access to achieve the required capacity and "colourless" transmitters will be a critical element to achieving this. Whilst the ONU is principal focus of attention for component cost reduction in a TDMA PON the symmetrical nature of a WDM-PON architecture means that the OLT cost must also be considered. Within the OLT photonic integration will be needed to reduce cost and footprint. Moreover, with the right choice of integration technology we believe it should ultimately be possible to achieve cooler-less operation of DWDM modules leading to significant reductions in power consumption. Components for next generation access should strive to be "compact, colourless and cooler-less"

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